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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SK3306B

SWITCHING N-CHANNEL POWER MOSFET

DESCRIPTION

The 2SK3306B is N-Channel MOSFET device that features a low gate charge and excellent switching characteristics, and designed for high voltage applications such as switching power supply, AC adapter.

FEATURES

Low gate charge

 $Q_G = 13 \text{ nC TYP.}$ ($V_{DD} = 400 \text{ V}$, $V_{GS} = 10 \text{ V}$, $I_D = 5.0 \text{ A}$)

• Gate voltage rating: ±30 V

· Low on-state resistance

 $R_{DS(on)}$ = 1.5 Ω MAX. (Vgs = 10 V, ID = 2.5 A)

• Avalanche capability ratings

(Isolated TO-220)



ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE		
2SK3306B-S17-AY Note	Pure Sn (Tin)	Tube 50 p/tube	Isolated TO-220 (MP-45F) typ. 2.2 g		

Note Pb-free (This product does not contain Pb in external electrode.)

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	500	V
Gate to Source Voltage (Vbs = 0 V)	Vgss	±30	V
Drain Current (DC) (Tc = 25°C)	Id(DC)	±5	Α
Drain Current (pulse) Note1	I _{D(pulse)}	±20	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	35	W
Total Power Dissipation	P _{T2}	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C
Single Avalanche Current Note2	las	5.0	Α
Single Avalanche Energy Note2	Eas	125	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 150 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

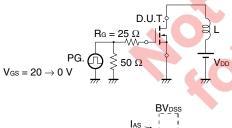
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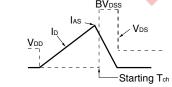
ELECTRICAL CHARACTERISTICS (TA = 25°C)

Characteristics	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 500 V, V _{GS} = 0 V			100	μΑ
Gate Leakage Current	Igss	V _{GS} = ±30 V, V _{DS} = 0 V			±100	nA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	2.5		3.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 10 V, I _D = 2.5 A	1.0	2.2		s
Drain to Source On-state Resistance Note	RDS(on)	V _{GS} = 10 V, I _D = 2.5 A		1.2	1.5	Ω
Input Capacitance	Ciss	V _{DS} = 10 V		730		pF
Output Capacitance	Coss	V _{GS} = 0 V		120		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		6		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 150 V, I _D = 2.5 A		13		ns
Rise Time	tr	V _{GS} = 10 V		7.5		ns
Turn-off Delay Time	t d(off)	R _G = 10 Ω		25		ns
Fall Time	tr	R _L = 60 Ω		6.5		ns
Total Gate Charge	Q _G	V _{DD} = 400 V		13		nC
Gate to Source Charge	Qgs	V _{GS} = 10 V		6		nC
Gate to Drain Charge	Q _{GD}	I _D = 5.0 A	3	4		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 5.0 A, V _{GS} = 0 V		0.9		V
Reverse Recovery Time	trr	I _F = 5.0 A, V _{GS} = 0 V		240		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		1200		nC

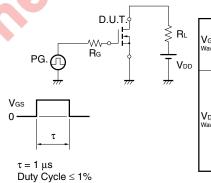
Note Pulsed

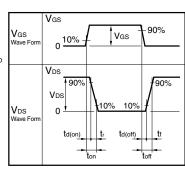
TEST CIRCUIT 1 AVALANCHE CAPABILITY





TEST CIRCUIT 2 SWITCHING TIME

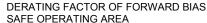


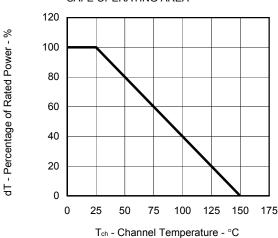


TEST CIRCUIT 3 GATE CHARGE

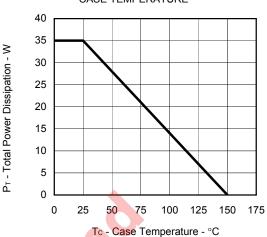
$$\begin{array}{c|c} D.U.T. \\ \hline I_G = 2 \text{ mA} \\ \hline \downarrow \\ \hline PG. \\ \hline \end{array} \begin{array}{c} S \\ \hline \end{array} \begin{array}{c} D.U.T. \\ \hline \end{array} \begin{array}{c} \\ \hline \end{array} \begin{array}{c} \\ \\ \\ \end{array} \begin{array}{c} \\ \\ \end{array} \begin{array}{c}$$

TYPICAL CHARACTERISTICS (TA = 25°C)

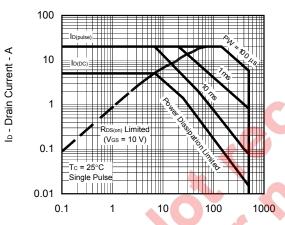




TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

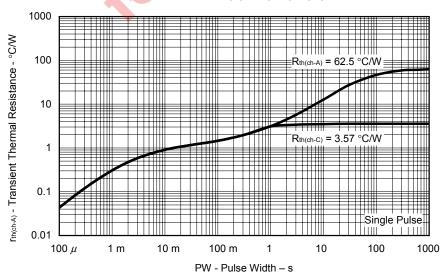


FORWARD BIAS SAFE OPERATING AREA



V_{DS} - Drain to Source Voltage - V

TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



1

VGS(off) - Gate Cut-off Voltage - V

0

2

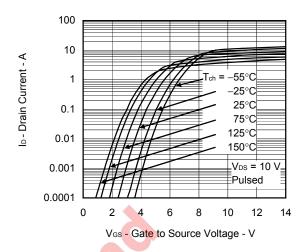
6 8 10

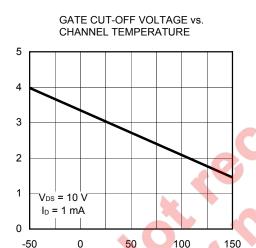
Pulsed-

16

12 14

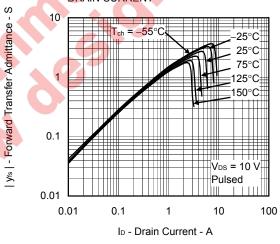


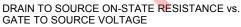




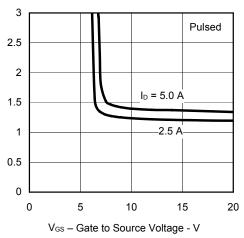
V_{DS} - Drain to Source Voltage - V

FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

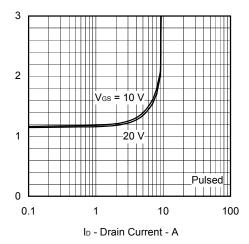




Tch - Channel Temperature - °C

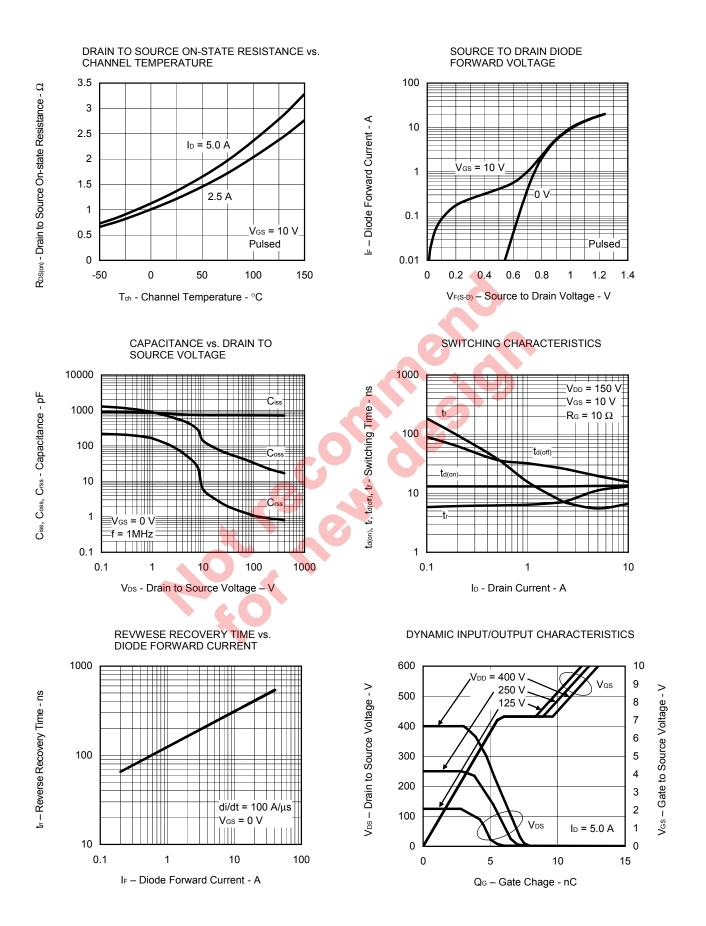


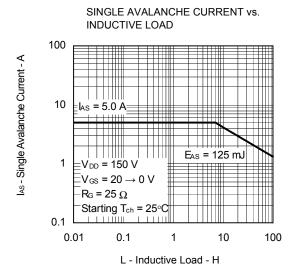
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



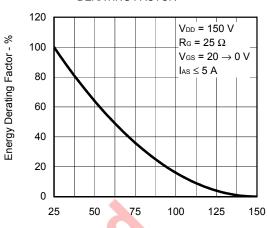
 $\mathsf{R}^{\mathsf{DS}(\mathsf{cm})}$ - Drain to Source On-state Resistance - Ω

 $\mathsf{R}_{\mathsf{DS}(on)}$ - Drain to Source On-state Resistance - Ω





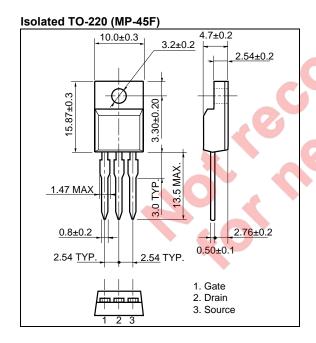
SINGLE AVALANCHE ENERGY DERATING FACTOR

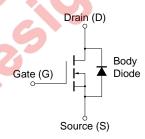


Starting Tch - Starting Channel Temperature - °C

PACKAGE DRAWING (Unit: mm)

EQUIVALENT CIRCUIT





Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

NEC 2SK3306B

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